

ISL83080E/82E/83E/84E/85E/86E/88E

±15kV ESD, 5V, Full Fail-Safe, 1/8 Unit Load, RS-485/RS-422 Transceivers

FN6085

Rev 10.00

February 15, 2016

The ISL8308xE are BiCMOS, ESD protected, 5V powered, single transceivers that meet both the RS-485 and RS-422 standards for balanced communication. Each driver output, and receiver input, is protected against ±15kV ESD strikes without latch-up, and unlike competitive products, this Intersil family is specified for 10% tolerance supplies (4.5V to 5.5V).

These devices have very low bus currents (+125μA/-75μA), so they present a true “1/8 unit load” to the RS-485 bus. This allows up to 256 transceivers on the network without violating the RS-485 specification's 32 unit load maximum, and without using repeaters. For example, in a remote utility meter reading system, individual meter readings are routed to a concentrator via an RS-485 network, so the high allowed node count minimizes the number of repeaters required. Data for all meters is then read out from the concentrator via a single access port, or a wireless link.

Receiver (Rx) inputs feature a “Full Fail-Safe” design, which ensures a logic high Rx output if Rx inputs are floating, shorted, or terminated but undriven.

The ISL83080E, ISL83082E, ISL83083E, ISL83084E, ISL83085E utilize slew rate limited drivers which reduce EMI, and minimize reflections from improperly terminated transmission lines, or unterminated stubs in multidrop and multipoint applications. Slew rate limited versions also include receiver input filtering to enhance noise immunity in the presence of slow input signals.

Hot Plug circuitry ensures that the Tx and Rx outputs remain in a high impedance state until the power supply has stabilized, and the Tx outputs are fully short circuit protected.

The ISL83080E, ISL83083E, ISL83084E, ISL83086E are configured for full duplex (separate Rx input and Tx output pins) applications. The half duplex versions multiplex the Rx inputs and Tx outputs to allow transceivers with output disable functions in 8 Ld packages.

Features

- Pb-Free Available (RoHS Compliant)
- RS-485 I/O Pin ESD Protection ±15kV HBM
Class 3 ESD Protection (HBM) on all Pins. >7kV
- Tiny MSOP Packages Save 50% Board Space
- Full Fail-Safe (Open, Short, Terminated and Floating) Receivers
- Hot Plug Circuitry (ISL83080E, ISL83082E, ISL83083E, ISL83085E)
 - Tx and Rx Outputs Remain Three-state During Power-up/Power-down
- True 1/8 Unit Load Allows up to 256 Devices on the Bus
- Specified for Single 5V, 10% Tolerance, Supplies
- High Data Rates up to 10Mbps
- Low Quiescent Supply Current 530μA
Ultra Low Shutdown Supply Current 70nA
- -7V to +12V Common Mode Input Voltage Range
- Half and Full Duplex Pinouts
- Three-State Rx and Tx Outputs (Except ISL83084E)
- Current Limiting and Thermal Shutdown for driver Overload Protection

Applications

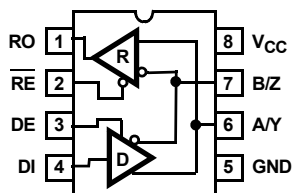
- Automated Utility Meter Reading Systems
- High Node Count Systems
- Factory Automation
- Field Bus Networks
- Security Camera Networks
- Building Environmental Control Systems
- Industrial/Process Control Networks

TABLE 1. SUMMARY OF FEATURES

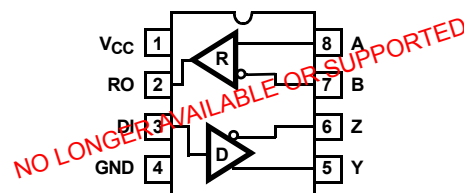
PART NUMBER	HALF/FULL DUPLEX	DATA RATE (Mbps)	SLEW- RATE LIMITED?	HOT PLUG	# DEVICES ON BUS	Rx/Tx ENABLE?	QUIESCEN T I _{CC} (μA)	LOW POWER SHUTDOWN?	PIN COUNT
ISL83080E	Full	0.115	Yes	Yes	256	Yes	530	Yes	10, 14
ISL83082E	Half	0.115	Yes	Yes	256	Yes	530	Yes	8
ISL83083E	Full	0.5	Yes	Yes	256	Yes	530	Yes	10, 14
ISL83084E (No longer available or supported)	Full	0.5	Yes	No	256	No	530	No	8
ISL83085E	Half	0.5	Yes	Yes	256	Yes	530	Yes	8
ISL83086E	Full	10	No	No	256	Yes	530	Yes	10, 14
ISL83088E	Half	10	No	No	256	Yes	530	Yes	8

Pinouts

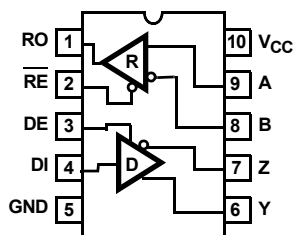
ISL83082E, ISL83085E, ISL83088E
(8 LD MSOP, SOIC)
TOP VIEW



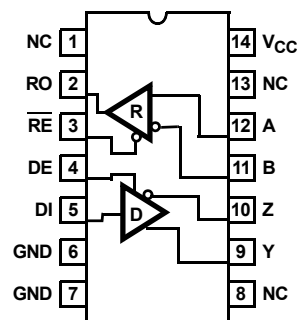
ISL83084E
(8 LD SOIC)
TOP VIEW



ISL83080E, ISL83083E, ISL83086E
(10 LD MSOP)
TOP VIEW



ISL83080E, ISL83083E, ISL83086E
(14 LD SOIC)
TOP VIEW



Ordering Information

PART NUMBER (Note 1)	PART MARKING	TEMP. RANGE (°C)	PACKAGE (RoHS Compliant)	PKG. DWG. #
ISL83080EIBZ (Note 2)	83080EIBZ	-40 to +85	14 Ld SOIC	M14.15
ISL83080EIUZ (Note 2)	3080Z	-40 to +85	10 Ld MSOP	M10.118
ISL83082EIBZ (Note 2)	83082 EIBZ	-40 to +85	8 Ld SOIC	M8.15
ISL83082EIUZ (Note 2)	3082Z	-40 to +85	8 Ld MSOP	M8.118
ISL83083EIBZ (Note 2)	83083EIBZ	-40 to +85	14 Ld SOIC	M14.15
ISL83083EIUZ (Note 2)	3083Z	-40 to +85	10 Ld MSOP	M10.118
ISL83084EIBZ (Note 2) (No longer available or supported, Recommended Replacements ISL83080EIBZ or ISL83088EIBZ)	83084 EIBZ	-40 to +85	8 Ld SOIC	M8.15
ISL83085EIBZ (Note 2)	83085 EIBZ	-40 to +85	8 Ld SOIC	M8.15
ISL83085EIUZ (Note 2)	3085Z	-40 to +85	8 Ld MSOP	M8.118
ISL83086EIBZ (Note 2)	83086EIBZ	-40 to +85	14 Ld SOIC	M14.15
ISL83086EIUZ (Note 2)	3086Z	-40 to +85	10 Ld MSOP	M10.118
ISL83088EIBZ (Note 2)	83088 EIBZ	-40 to +85	8 Ld SOIC	M8.15
ISL83088EIUZ (Note 2)	3088Z	-40 to +85	8 Ld MSOP	M8.118

NOTES:

1. Add "-T" suffix for tape and reel. Please refer to TB347 for details on reel specifications.
2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Truth Tables

TRANSMITTING				
INPUTS			OUTPUTS	
$\overline{RE}$	DE	DI	Z	Y
X	1	1	0	1
X	1	0	1	0
0	0	X	High-Z	High-Z
1	0	X	High-Z *	High-Z*

NOTE: *Shutdown Mode (See Notes 10 and 13).

RECEIVING				
INPUTS				OUTPUT
$\overline{RE}$	DE Half Duplex	DE Full Duplex	A-B	RO
0	0	X	$\geq -0.05V$	1
0	0	X	$\leq -0.2V$	0
0	0	X	Inputs Open/Shorted	1
1	0	0	X	High-Z*
1	1	1	X	High-Z

NOTE: *Shutdown Mode (See Notes 10 and 13).

Pin Descriptions

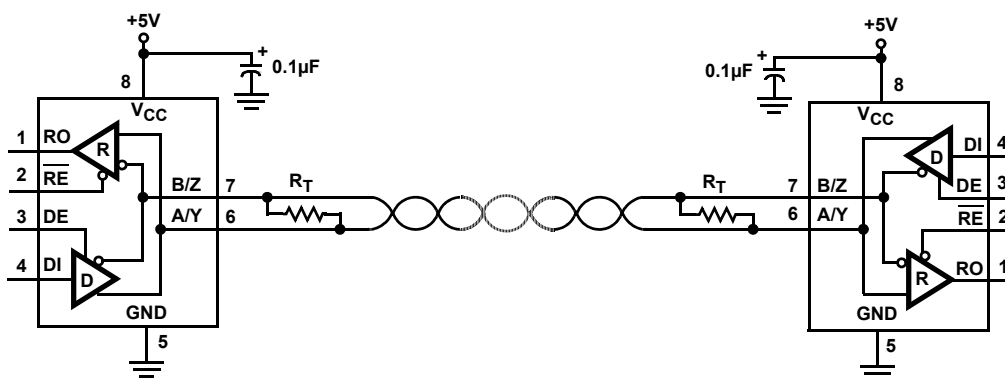
PIN	FUNCTION
RO	Receiver output: If A - B $\geq$ -50mV, RO is high; If A - B $\leq$ -200mV, RO is low; RO = High if A and B are unconnected (floating) or shorted.
$\overline{RE}$	Receiver output enable. RO is enabled when $\overline{RE}$ is low; RO is high impedance when $\overline{RE}$ is high.
DE	Driver output enable. The driver outputs, Y and Z, are enabled by bringing DE high. They are high impedance when DE is low.

Pin Descriptions (Continued)

PIN	FUNCTION
DI	Driver input. A low on DI forces output Y low and output Z high. Similarly, a high on DI forces output Y high and output Z low.
GND	Ground connection.
A/Y	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, noninverting receiver input and noninverting driver output. Pin is an input if DE = 0; pin is an output if DE = 1.
B/Z	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, Inverting receiver input and inverting driver output. Pin is an input if DE = 0; pin is an output if DE = 1.
A	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, noninverting receiver input.
B	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, inverting receiver input.
Y	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, noninverting driver output.
Z	$\pm 15\text{kV}$ HBM ESD Protected RS-485/RS-422 level, inverting driver output.
V _{CC}	System power supply input (4.5V to 5.5V).
NC	No Connection.

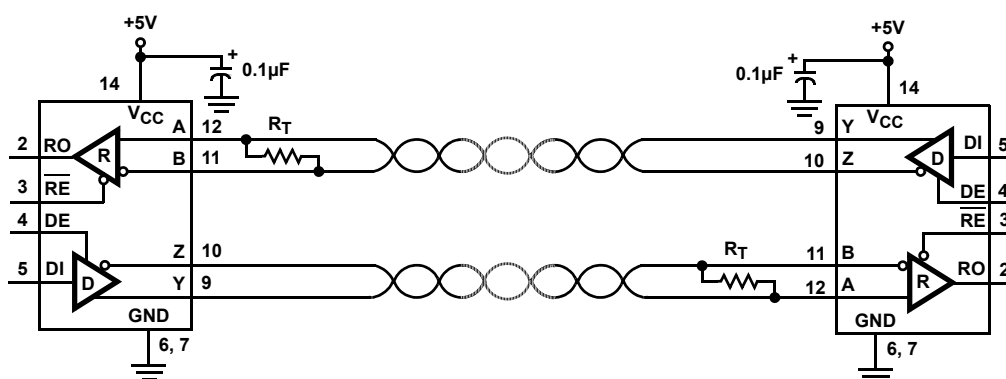
Typical Operating Circuit

ISL83082E, ISL83085E, ISL83088E

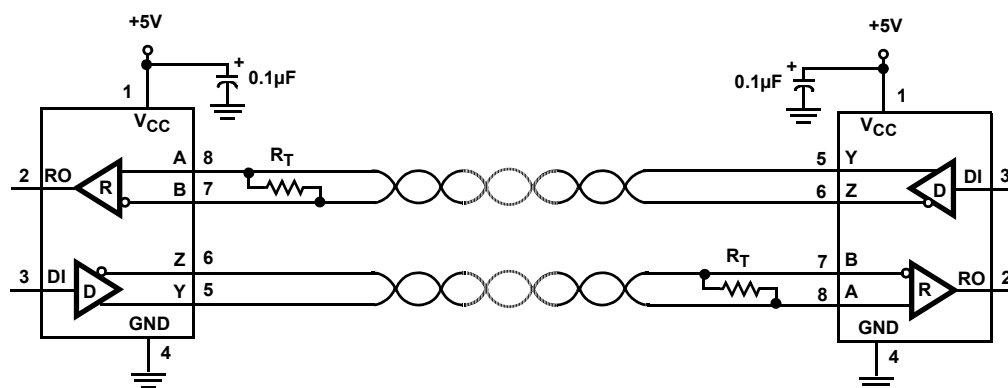


Typical Operating Circuit (Continued)

ISL83080E, ISL83083E, ISL83086E



ISL83084E



Absolute Maximum Ratings

V _{CC} to Ground	7V
Input Voltages	
DI, DE, RE	-0.3V to (V _{CC} + 0.3V)
Input/Output Voltages	
A, B, Y, Z	-9V to +13V
A, B, Y, Z (Transient Pulse Through 100Ω, Note 14)	±75V
RO	-0.3V to (V _{CC} + 0.3V)
Short Circuit Duration	
Y, Z	Continuous
ESD Rating	See Specification Table

Thermal Information

Thermal Resistance (Typical, Note 3)	θ _{JA} (°C/W)
8 Ld SOIC Package	105
8 Ld MSOP Package	140
10 Ld MSOP Package	190
14 Ld SOIC Package	128
Maximum Junction Temperature (Plastic Package)	+150°C
Maximum Storage Temperature Range	-65°C to +150°C
Pb-free reflow profile	see link below
http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

Operating Conditions

Temperature Range	-40°C to +85°C
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CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTE:

- θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

Electrical Specifications Test Conditions: V_{CC} = 4.5V to 5.5V; Unless Otherwise Specified. Typicals are at V_{CC} = 5V, T_A = +25°C (Note 5).

PARAMETER	SYMBOL	TEST CONDITIONS		TEMP (°C)	MIN (Note 4)	TYP	MAX (Note 4)	UNITS
DC CHARACTERISTICS								
Driver Differential V _{OUT} (no load)	V _{OD1}			Full	-	-	V _{CC}	V
Driver Differential V _{OUT} (with load)	V _{OD2}	R _L = 100Ω (RS-422) (Figure 1A)		Full	2	2.9	-	V
		R _L = 54Ω (RS-485) (Figure 1A)		Full	1.5	2.4	V _{CC}	V
		R _L = 60Ω, -7V ≤ V _{CM} ≤ 12V (Figure 1B)		Full	1.5	2.6	-	V
Change in Magnitude of Driver Differential V _{OUT} for Complementary Output States	ΔV _{OD}	R _L = 54Ω or 100Ω (Figure 1A)		Full	-	0.01	0.2	V
Driver Common-Mode V _{OUT}	V _{OC}	R _L = 54Ω or 100Ω (Figure 1A)		Full	-	2.85	3	V
Change in Magnitude of Driver Common-Mode V _{OUT} for Complementary Output States	ΔV _{OC}	R _L = 54Ω or 100Ω (Figure 1A)		Full	-	0.01	0.1	V
Logic Input High Voltage	V _{IH}	DE, DI, $\overline{RE}$		Full	2	-	-	V
Logic Input Low Voltage	V _{IL}	DE, DI, $\overline{RE}$		Full	-	-	0.8	V
DI Input Hysteresis Voltage	V _{HYS}			25	-	100	-	mV
Logic Input Current	I _{IN1}	DE, DI, $\overline{RE}$		Full	-2	-	2	μA
Input Current (A, B)	I _{IN2}	DE = 0V, V _{CC} = 0V or 5.5V	V _{IN} = 12V	Full	-	70	125	μA
			V _{IN} = -7V	Full	-75	55	-	μA
Output Leakage Current (Y, Z) (Full Duplex Versions Only)	I _{IN3}	$\overline{RE}$ = 0V, DE = 0V, V _{CC} = 0V or 5.5V (Note 13)	V _{IN} = 12V	Full	-	7	125	μA
			V _{IN} = -7V	Full	-75	11	-	μA
Output Leakage Current (Y, Z) in Shutdown Mode (Full Duplex)	I _{IN3}	$\overline{RE}$ = V _{CC} , DE = 0V, V _{CC} = 0V or 5.5V (Note 13)	V _{IN} = 12V	Full	-	0	20	μA
			V _{IN} = -7V	Full	-20	9	-	μA
Driver Short-Circuit Current, V _O = High or Low	I _{OSD1}	DE = V _{CC} , -7V ≤ V _Y or V _Z ≤ 12V (Note 7)		Full	-	-	±250	mA

Electrical Specifications Test Conditions: $V_{CC} = 4.5V$ to $5.5V$; Unless Otherwise Specified. Typical values are at $V_{CC} = 5V$, $T_A = +25^\circ C$ (Note 5). **(Continued)**

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 4)	TYP	MAX (Note 4)	UNITS
Receiver Differential Threshold Voltage	V _{TH}	-7V ≤ V _{CM} ≤ 12V	Full	-200	-90	-50	mV
Receiver Input Hysteresis	ΔV _{TH}	V _{CM} = 0V	25	-	20	-	mV
Receiver Output High Voltage	V _{OH}	I _O = -4mA, V _{ID} = -50mV	Full	V _{CC} - 1	4.6	-	V
Receiver Output Low Voltage	V _{OL}	I _O = -4mA, V _{ID} = -200mV	Full	-	0.2	0.4	V
Three-State (high impedance) Receiver Output Current	I _{OZR}	0.4V ≤ V _O ≤ 2.4V (Note 13)	Full	-1	0.03	1	μA
Receiver Input Resistance	R _{IN}	-7V ≤ V _{CM} ≤ 12V	Full	96	160	-	kΩ
Receiver Short-Circuit Current	I _{OSR}	0V ≤ V _O ≤ V _{CC}	Full	±7	-	±85	mA
SUPPLY CURRENT							
No-Load Supply Current (Note 6)	I _{CC}	Half Duplex Versions, DE = V _{CC} , $\overline{RE}$ = X, DI = 0V or V _{CC}	Full	-	560	700	μA
		All Versions, DE = 0V, $\overline{RE}$ = 0V, or Full Duplex Versions, DE = V _{CC} , $\overline{RE}$ = X. DI = 0V or V _{CC}	Full	-	530	650	μA
Shutdown Supply Current	I _{SHDN}	DE = 0V, $\overline{RE}$ = V _{CC} , DI = 0V or V _{CC} (Note 13)	Full	-	0.07	2	μA
ESD PERFORMANCE							
RS-485 Pins (A, Y, B, Z)		Human Body Model (HBM), Pin to GND	25	-	±15	-	kV
All Other Pins		HBM, per MIL-STD-883 Method 3015	25	-	±7	-	kV
		Machine Model	25	-	> ±250	-	V
DRIVER SWITCHING CHARACTERISTICS (115kbps Versions; ISL83080E, ISL83082E)							
Driver Differential Output Delay	t _{PLH} , t _{PHL}	R _{DIFF} = 54Ω, C _L = 100pF (Figure 2)	Full	500	780	1300	ns
Driver Differential Output Skew	t _{SKEW}	R _{DIFF} = 54Ω, C _L = 100pF (Figure 2)	Full	-	40	100	ns
Driver Differential Rise or Fall Time	t _R , t _F	R _{DIFF} = 54Ω, C _L = 100pF (Figure 2)	Full	667	1000	1500	ns
Maximum Data Rate	f _{MAX}	C _D = 820pF (Figure 4) (Note 15)	Full	115	666	-	kbps
Driver Enable to Output High	t _{ZH}	R _L = 500Ω, C _L = 100pF, SW = GND (Figure 3), (Note 8)	Full	-	278	1500	ns
Driver Enable to Output Low	t _{ZL}	R _L = 500Ω, C _L = 100pF, SW = V _{CC} (Figure 3) (Note 8)	Full	-	35	1500	ns
Driver Disable from Output Low	t _{LZ}	R _L = 500Ω, C _L = 15pF, SW = V _{CC} (Figure 3)	Full	-	67	100	ns
Driver Disable from Output High	t _{HZ}	R _L = 500Ω, C _L = 15pF, SW = GND (Figure 3)	Full	-	38	100	ns
Time to Shutdown	t _{SHDN}	(Note 10)	Full	60	160	600	ns
Driver Enable from Shutdown to Output High	t _{ZH(SHDN)}	R _L = 500Ω, C _L = 100pF, SW = GND (Figure 3) (Notes 10, 11)	Full	-	400	2000	ns
Driver Enable from Shutdown to Output Low	t _{ZL(SHDN)}	R _L = 500Ω, C _L = 100pF, SW = V _{CC} (Figure 3) (Notes 10, 11)	Full	-	155	2000	ns
DRIVER SWITCHING CHARACTERISTICS (500kbps Versions; ISL83083E, ISL83084E, ISL83085E)							
Driver Differential Output Delay	t _{PLH} , t _{PHL}	R _{DIFF} = 54Ω, C _L = 100pF (Figure 2)	Full	250	360	1000	ns
Driver Differential Output Skew	t _{SKEW}	R _{DIFF} = 54Ω, C _L = 100pF (Figure 2)	Full	-	20	100	ns
Driver Differential Rise or Fall Time	t _R , t _F	R _{DIFF} = 54Ω, C _L = 100pF (Figure 2)	Full	200	475	750	ns
Maximum Data Rate	f _{MAX}	C _D = 820pF (Figure 4) (Note 15)	Full	500	1000	-	kbps

Electrical Specifications Test Conditions: $V_{CC} = 4.5V$ to $5.5V$; Unless Otherwise Specified. Typical values are at $V_{CC} = 5V$, $T_A = +25^\circ C$ (Note 5). (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 4)	TYP	MAX (Note 4)	UNITS
Driver Enable to Output High	t_{ZH}	$R_L = 500\Omega$, $C_L = 100pF$, SW = GND (Figure 3), (Notes 8, 13)	Full	-	137	1000	ns
Driver Enable to Output Low	t_{ZL}	$R_L = 500\Omega$, $C_L = 100pF$, SW = V_{CC} (Figure 3), (Notes 8, 13)	Full	-	35	1000	ns
Driver Disable from Output Low	t_{LZ}	$R_L = 500\Omega$, $C_L = 15pF$, SW = V_{CC} (Figure 3), (Note 13)	Full	-	65	100	ns
Driver Disable from Output High	t_{HZ}	$R_L = 500\Omega$, $C_L = 15pF$, SW = GND (Figure 3), (Note 13)	Full	-	38	100	ns
Time to Shutdown	t_{SHDN}	(Note 10)	Full	60	160	600	ns
Driver Enable from Shutdown to Output High	$t_{ZH}(SHDN)$	$R_L = 500\Omega$, $C_L = 100pF$, SW = GND (Figure 3), (Notes 10, 11, 13)	Full	-	260	1500	ns
Driver Enable from Shutdown to Output Low	$t_{ZL}(SHDN)$	$R_L = 500\Omega$, $C_L = 100pF$, SW = V_{CC} (Figure 3), (Notes 10, 11, 13)	Full	-	155	1500	ns
DRIVER SWITCHING CHARACTERISTICS (10Mbps Versions; ISL83086E, ISL83088E)							
Driver Differential Output Delay	t_{PLH}, t_{PHL}	$R_{DIFF} = 54\Omega$, $C_L = 100pF$ (Figure 2)	Full	-	20	60	ns
Driver Differential Output Skew	t_{SKEW}	$R_{DIFF} = 54\Omega$, $C_L = 100pF$ (Figure 2)	Full	-	1	10	ns
Driver Differential Rise or Fall Time	t_R, t_F	$R_{DIFF} = 54\Omega$, $C_L = 100pF$ (Figure 2)	Full	-	13	25	ns
Maximum Data Rate	f_{MAX}	$C_D = 470pF$ (Figure 4) (Note 15)	Full	10	15	-	Mbps
Driver Enable to Output High	t_{ZH}	$R_L = 500\Omega$, $C_L = 100pF$, SW = GND (Figure 3), (Note 8)	Full	-	35	150	ns
Driver Enable to Output Low	t_{ZL}	$R_L = 500\Omega$, $C_L = 100pF$, SW = V_{CC} (Figure 3), (Note 8)	Full	-	30	150	ns
Driver Disable from Output Low	t_{LZ}	$R_L = 500\Omega$, $C_L = 15pF$, SW = V_{CC} (Figure 3)	Full	-	66	100	ns
Driver Disable from Output High	t_{HZ}	$R_L = 500\Omega$, $C_L = 15pF$, SW = GND (Figure 3)	Full	-	38	100	ns
Time to Shutdown	t_{SHDN}	(Note 10)	Full	60	160	600	ns
Driver Enable from Shutdown to Output High	$t_{ZH}(SHDN)$	$R_L = 500\Omega$, $C_L = 100pF$, SW = GND (Figure 3), (Notes 10, 11)	Full	-	115	250	ns
Driver Enable from Shutdown to Output Low	$t_{ZL}(SHDN)$	$R_L = 500\Omega$, $C_L = 100pF$, SW = V_{CC} (Figure 3), (Notes 10, 11)	Full	-	84	250	ns
RECEIVER SWITCHING CHARACTERISTICS (115kbps and 500kbps Versions; ISL83080E THRU ISL83085E)							
Maximum Data Rate	f_{MAX}	(Figure 5) (Note 15)	Full	0.5	10	-	Mbps
Receiver Input to Output Delay	t_{PLH}, t_{PHL}	(Figure 5)	Full	-	100	150	ns
Receiver Skew $t_{PLH} - t_{PHL}$	t_{SKD}	(Figure 5)	Full	-	7	10	ns
Receiver Enable to Output Low	t_{ZL}	$R_L = 1k\Omega$, $C_L = 15pF$, SW = V_{CC} (Figure 6), (Notes 9, 13)	Full	-	10	50	ns
Receiver Enable to Output High	t_{ZH}	$R_L = 1k\Omega$, $C_L = 15pF$, SW = GND (Figure 6), (Notes 9, 13)	Full	-	10	50	ns
Receiver Disable from Output Low	t_{LZ}	$R_L = 1k\Omega$, $C_L = 15pF$, SW = V_{CC} (Figure 6), (Note 13)	Full	-	10	50	ns
Receiver Disable from Output High	t_{HZ}	$R_L = 1k\Omega$, $C_L = 15pF$, SW = GND (Figure 6), (Note 13)	Full	-	10	50	ns
Time to Shutdown	t_{SHDN}	(Notes 10, 13)	Full	60	160	600	ns

Electrical Specifications Test Conditions: $V_{CC} = 4.5V$ to $5.5V$; Unless Otherwise Specified. Typical values are at $V_{CC} = 5V$, $T_A = +25^\circ C$ (Note 5). (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 4)	TYP	MAX (Note 4)	UNITS
Receiver Enable from Shutdown to Output High	$t_{ZH}(SHDN)$	$R_L = 1k\Omega$, $C_L = 15pF$, $SW = GND$ (Figure 6), (Notes 10, 12, 13)	Full	-	150	2000	ns
Receiver Enable from Shutdown to Output Low	$t_{ZL}(SHDN)$	$R_L = 1k\Omega$, $C_L = 15pF$, $SW = V_{CC}$ (Figure 6), (Notes 10, 12, 13)	Full	-	150	2000	ns
RECEIVER SWITCHING CHARACTERISTICS (10Mbps Versions; ISL83086E, ISL83088E)							
Maximum Data Rate	f_{MAX}	(Figure 5) (Note 15)	Full	10	15	-	Mbps
Receiver Input to Output Delay	t_{PLH} , t_{PHL}	(Figure 5)	Full	-	70	125	ns
Receiver Skew $t_{PLH} - t_{PHL}$	t_{SKD}	(Figure 5)	Full	-	0	10	ns
Receiver Enable to Output Low	t_{ZL}	$R_L = 1k\Omega$, $C_L = 15pF$, $SW = V_{CC}$ (Figure 6) (Note 9)	Full	-	10	30	ns
Receiver Enable to Output High	t_{ZH}	$R_L = 1k\Omega$, $C_L = 15pF$, $SW = GND$ (Figure 6) (Note 9)	Full	-	10	30	ns
Receiver Disable from Output Low	t_{LZ}	$R_L = 1k\Omega$, $C_L = 15pF$, $SW = V_{CC}$ (Figure 6)	Full	-	10	30	ns
Receiver Disable from Output High	t_{HZ}	$R_L = 1k\Omega$, $C_L = 15pF$, $SW = GND$ (Figure 6)	Full	-	10	30	ns
Time to Shutdown	t_{SHDN}	(Note 10)	Full	60	160	600	ns
Receiver Enable from Shutdown to Output High	$t_{ZH}(SHDN)$	$R_L = 1k\Omega$, $C_L = 15pF$, $SW = GND$ (Figure 6) (Notes 10, 12)	Full	-	150	2000	ns
Receiver Enable from Shutdown to Output Low	$t_{ZL}(SHDN)$	$R_L = 1k\Omega$, $C_L = 15pF$, $SW = V_{CC}$ (Figure 6) (Notes 10, 12)	Full	-	150	2000	ns

NOTES:

- Parameters with MIN and/or MAX limits are 100% tested at $+25^\circ C$, unless otherwise specified. Temperature limits established by characterization and are not production tested.
- All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to device ground unless otherwise specified.
- Supply current specification is valid for loaded drivers when $DE = 0V$.
- Applies to peak current. See "Typical Performance Curves" beginning on page 13 for more information.
- Keep $\overline{RE} = 0$ to prevent the device from entering SHDN.
- The $\overline{RE}$ signal high time must be short enough (typically $<100ns$) to prevent the device from entering SHDN.
- Transceivers are put into shutdown by bringing $\overline{RE}$ high and DE low. If the inputs are in this state for less than 60ns, the parts are guaranteed not to enter shutdown. If the inputs are in this state for at least 600ns, the parts are guaranteed to have entered shutdown. See "Low Power Shutdown Mode" on page 13.
- Keep $\overline{RE} = V_{CC}$, and set the DE signal low time $>600ns$ to ensure that the device enters SHDN.
- Set the $\overline{RE}$ signal high time $>600ns$ to ensure that the device enters SHDN.
- Does not apply to the ISL83084E.
- Tested according to TIA/EIA-485-A, section 4.2.6 ($\pm 75V$ for $15\mu s$ at a 1% duty cycle).
- Limits established by characterization and are not production tested.

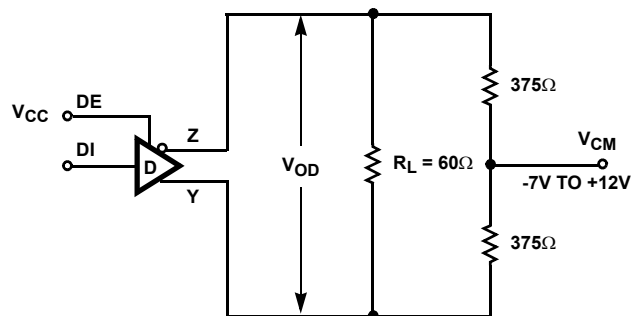
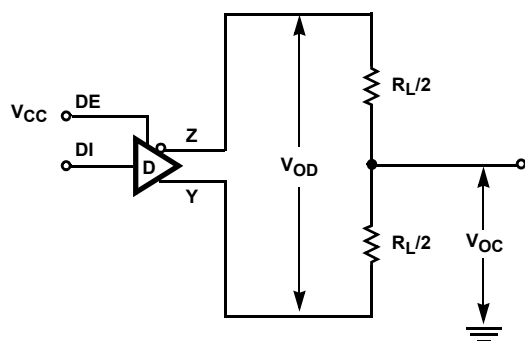


FIGURE 1A. V_{OD} AND V_{OC}

FIGURE 1B. V_{OD} WITH COMMON MODE LOAD

FIGURE 1. DC DRIVER TEST CIRCUITS

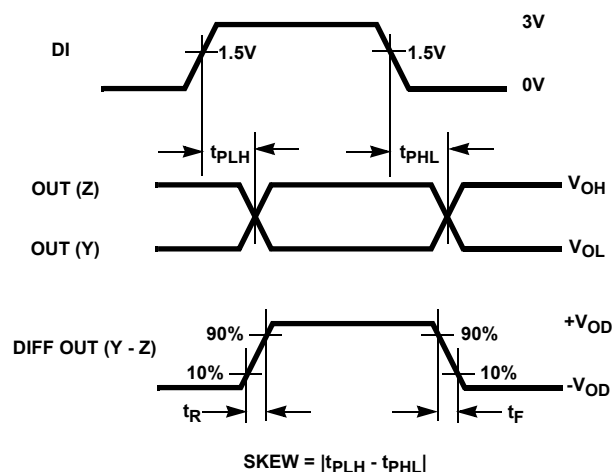
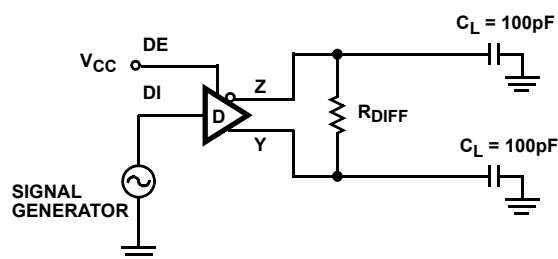
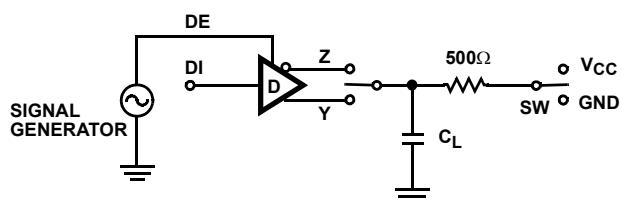


FIGURE 2A. TEST CIRCUIT

FIGURE 2B. MEASUREMENT POINTS

FIGURE 2. DRIVER PROPAGATION DELAY AND DIFFERENTIAL TRANSITION TIMES



PARAMETER	OUTPUT	$\overline{\text{RE}}$	DI	SW	C _L (pF)
t _{HZ}	Y/Z	X	1/0	GND	15
t _{LZ}	Y/Z	X	0/1	V _{CC}	15
t _{ZH}	Y/Z	0 (Note 8)	1/0	GND	100
t _{ZL}	Y/Z	0 (Note 8)	0/1	V _{CC}	100
t _{ZH} (SHDN)	Y/Z	1 (Note 11)	1/0	GND	100
t _{ZL} (SHDN)	Y/Z	1 (Note 11)	0/1	V _{CC}	100

FIGURE 3A. TEST CIRCUIT

FIGURE 3B. MEASUREMENT POINTS

FIGURE 3. DRIVER ENABLE AND DISABLE TIMES (DOES NOT APPLY TO THE ISL83084E)



FIGURE 5A. TEST CIRCUIT



PARAMETER	DE	A	SW
t _{HZ}	0	+1.5V	GND
t _{LZ}	0	-1.5V	V _{CC}
t _{ZH} (Note 9)	0	+1.5V	GND
t _{ZL} (Note 9)	0	-1.5V	V _{CC}
t _{ZH} (SHDN) (Note 12)	0	+1.5V	GND
t _{ZL} (SHDN) (Note 12)	0	-1.5V	V _{CC}

FIGURE 6A. TEST CIRCUIT

FIGURE 6. RECEIVER ENABLE AND DISABLE TIMES (DOES NOT APPLY TO THE ISL83084E)



one driver and up to 10 (assuming one unit load devices) receivers on each bus. RS-485 is a true multipoint standard, which allows up to 32 one unit load devices (any combination of drivers and receivers) on each bus. To allow for multipoint operation, the RS-485 specification requires that drivers must handle bus contention without sustaining any damage.

Another important advantage of RS-485 is the extended common mode range (CMR), which specifies that the driver outputs and receiver inputs withstand signals that range from +12V to -7V. RS-422 and RS-485 are intended for runs as long as 4000', so the wide CMR is necessary to handle ground potential differences, as well as voltages induced in the cable by external fields.

Receiver Features

These devices utilize a differential input receiver for maximum noise immunity and common mode rejection. Input sensitivity is $\pm 200\text{mV}$, as required by the RS-422 and RS-485 specifications.

Receiver input resistance of $96\text{k}\Omega$ surpasses the RS-422 specification of $4\text{k}\Omega$, and is eight times the RS-485 "Unit Load (UL)" requirement of $12\text{k}\Omega$ minimum. Thus, these products are known as "one-eighth UL" transceivers, and there can be up to 256 of these devices on a network while still complying with the RS-485 loading specification.

Receiver inputs function with common mode voltages as great as $\pm 7\text{V}$ outside the power supplies (i.e., +12V and -7V), making them ideal for long networks where induced voltages are a realistic concern.

All the receivers include a "full fail-safe" function that guarantees a high level receiver output if the receiver inputs are unconnected (floating) or shorted.

Receivers easily meet the data rates supported by the corresponding driver, and all receiver outputs are three-statable via the active low $\overline{\text{RE}}$ input (except for the ISL83084E).

Driver Features

The RS-485/RS-422 driver is a differential output device that delivers at least 1.5V across a 54Ω load (RS-485), and at least 2V across a 100Ω load (RS-422). The drivers feature low propagation delay skew to maximize bit width, and to minimize EMI.

All drivers are three-statable via the active high DE input (except for the ISL83084E).

The 115kbps and 500kbps driver outputs are slew rate limited to minimize EMI, and to minimize reflections in unterminated or improperly terminated networks. Outputs of the ISL83086E, ISL83088E drivers are not limited, so faster output transition times allow data rates of at least 10Mbps.

Hot Plug Function

When a piece of equipment powers up, there is a period of time where the processor or ASIC driving the RS-485 control lines (DE, $\overline{\text{RE}}$) is unable to ensure that the RS-485 Tx and Rx outputs are kept disabled. If the equipment is connected to the bus, a driver activating prematurely during power-up may crash the bus. To avoid this scenario, the ISL83080, ISL83082, ISL83083, ISL83085 versions incorporate a "Hot Plug" function. Circuitry monitoring V_{CC} ensures that, during

power-up and power-down, the Tx and Rx outputs remain disabled, regardless of the state of DE and $\overline{\text{RE}}$, if V_{CC} is less than $\sim 3.4\text{V}$. This gives the processor/ASIC a chance to stabilize and drive the RS-485 control lines to the proper states.

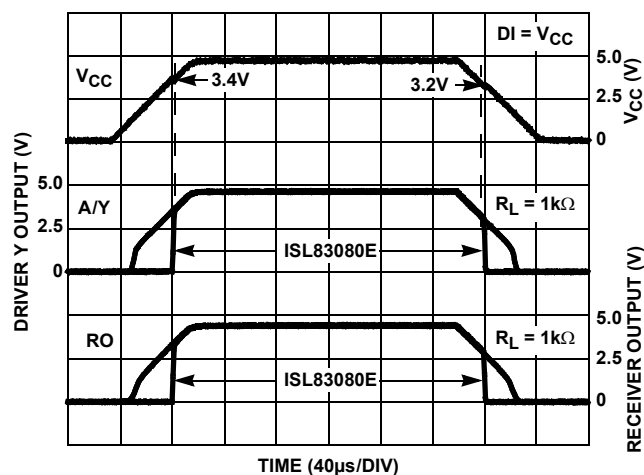


FIGURE 7. HOT PLUG PERFORMANCE (ISL83080E) vs DEVICE WITHOUT HOT PLUG CIRCUITRY (ISL83086E)

ESD Protection

All pins on these devices include class 3 Human Body Model (HBM) ESD protection structures, but the RS-485 pins (driver outputs and receiver inputs) incorporate advanced structures allowing them to survive ESD events in excess of $\pm 15\text{kV}$ HBM. The RS-485 pins are particularly vulnerable to ESD damage because they typically connect to an exposed port on the exterior of the finished product. Simply touching the port pins, or connecting a cable, can cause an ESD event that might destroy unprotected ICs. These new ESD structures protect the device whether or not it is powered up, protect without allowing any latchup mechanism to activate, and without degrading the RS-485 common mode range of -7V to +12V. This built-in ESD protection eliminates the need for board level protection structures (e.g., transient suppression diodes), and the associated, undesirable capacitive load they present.

Data Rate, Cables, and Terminations

RS-485/RS-422 are intended for network lengths up to 4000', but the maximum system data rate decreases as the transmission length increases. Devices operating at 10Mbps are limited to lengths less than 100', while the 115kbps versions can operate at full data rates with lengths of several 1000'.

Twisted pair is the cable of choice for RS-485/RS-422 networks. Twisted pair cables tend to pick up noise and other electromagnetically induced voltages as common mode signals, which are effectively rejected by the differential receivers in these ICs.

Proper termination is imperative (when using the 10Mbps devices) to minimize reflections. Short networks using the

115kbps versions need not be terminated, but, terminations are recommended unless power dissipation is an overriding concern.

In point-to-point, or point-to-multipoint (single driver on bus) networks, the main cable should be terminated in its characteristic impedance (typically 120Ω) at the end farthest from the driver. In multi-receiver applications, stubs connecting receivers to the main cable should be kept as short as possible. Multipoint (multi-driver) systems require that the main cable be terminated in its characteristic impedance at both ends. Stubs connecting a transceiver to the main cable should be kept as short as possible.

Built-In Driver Overload Protection

As stated previously, the RS-485 specification requires that drivers survive worst case bus contentions undamaged. These devices meet this requirement via driver output short circuit current limits, and on-chip thermal shutdown circuitry.

The driver output stages incorporate short circuit current limiting circuitry which ensures that the output current never exceeds the RS-485 specification, even at the common mode voltage range extremes. Additionally, these devices utilize a foldback circuit which reduces the short circuit current, and thus the power dissipation, whenever the contending voltage exceeds either supply.

In the event of a major short circuit condition, devices also include a thermal shutdown feature that disables the drivers whenever the die temperature becomes excessive. This eliminates the power dissipation, allowing the die to cool. The drivers automatically re-enable after the die temperature drops about $+15^{\circ}\text{C}$. If the contention persists, the thermal shutdown/re-enable cycle repeats until the fault is cleared. Receivers stay operational during thermal shutdown.

Low Power Shutdown Mode

These CMOS transceivers all use a fraction of the power required by their bipolar counterparts, but they also include a shutdown feature (except for the ISL83084E) that reduces the already low quiescent I_{CC} to a 70nA trickle. These devices enter shutdown whenever the receiver and driver are **simultaneously** disabled ($\text{RE} = V_{CC}$ and $\text{DE} = \text{GND}$) for a period of at least 600ns. Disabling both the driver and the receiver for less than 60ns guarantees that the transceiver will not enter shutdown.

Note that receiver and driver enable times increase when the transceiver enables from shutdown. Refer to Notes 8 thru 12, at the end of the "Electrical Specification Table" on page 9, for more information.

Typical Performance Curves $V_{CC} = 5\text{V}$, $T_A = +25^{\circ}\text{C}$; Unless Otherwise Specified

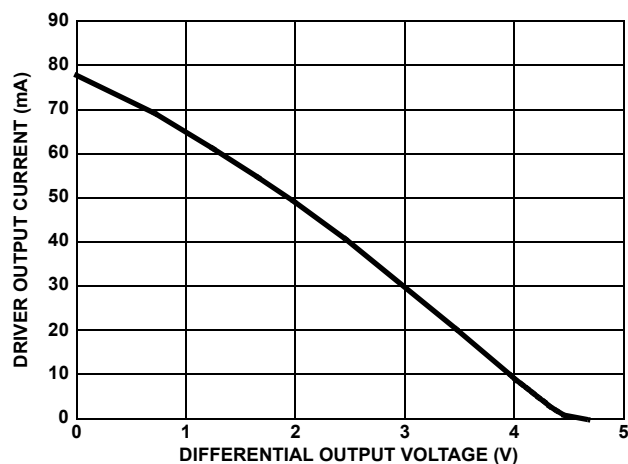


FIGURE 8. DRIVER OUTPUT CURRENT vs DIFFERENTIAL OUTPUT VOLTAGE

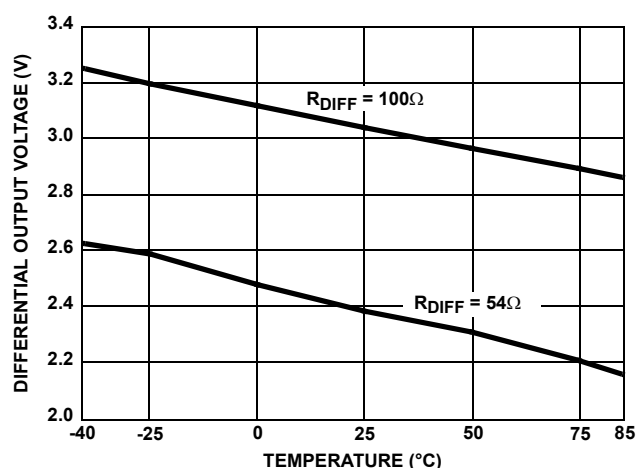


FIGURE 9. DRIVER DIFFERENTIAL OUTPUT VOLTAGE vs TEMPERATURE

Typical Performance Curves $V_{CC} = 5V$, $T_A = +25^\circ C$; Unless Otherwise Specified (Continued)

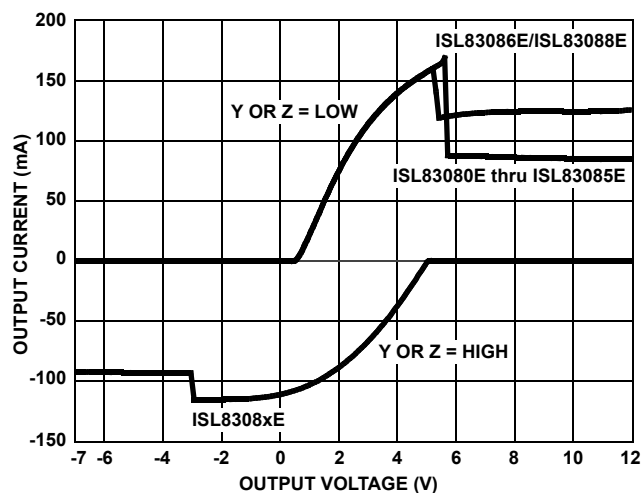


FIGURE 10. DRIVER OUTPUT CURRENT vs SHORT CIRCUIT VOLTAGE

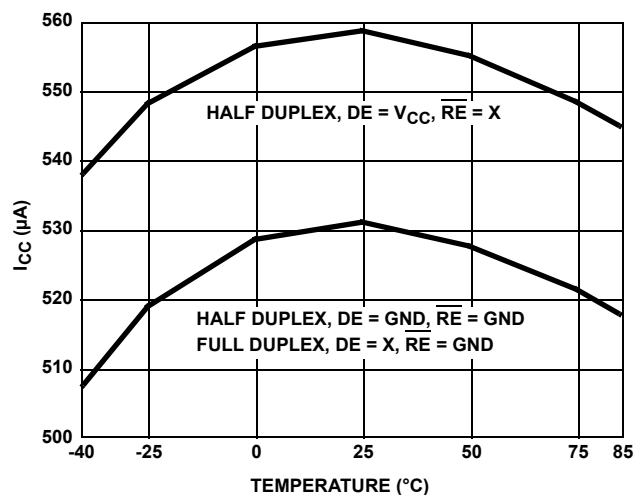


FIGURE 11. SUPPLY CURRENT vs TEMPERATURE

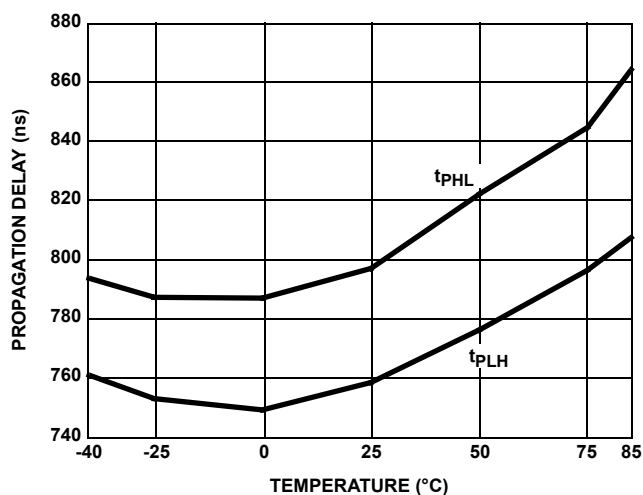


FIGURE 12. DRIVER DIFFERENTIAL PROPAGATION DELAY vs TEMPERATURE (ISL83080E, ISL83082E)

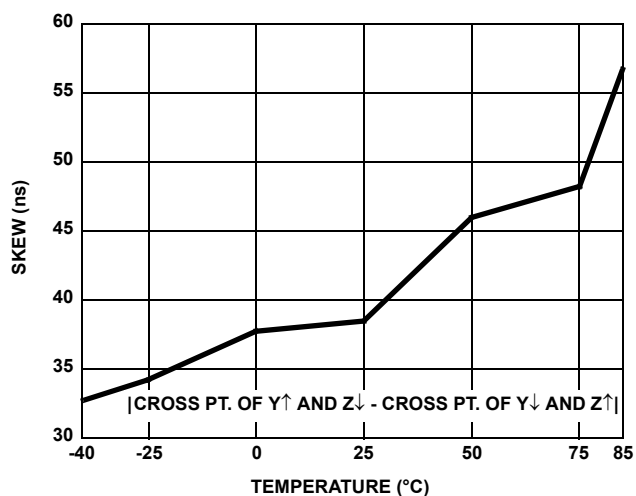


FIGURE 13. DRIVER DIFFERENTIAL SKEW vs TEMPERATURE (ISL83080E, ISL83082E)

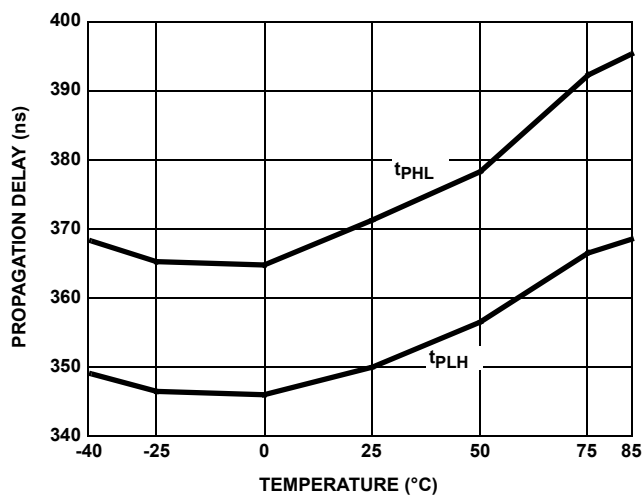


FIGURE 14. DRIVER DIFFERENTIAL PROPAGATION DELAY vs TEMPERATURE (ISL83083E, ISL83084E, ISL83085E)

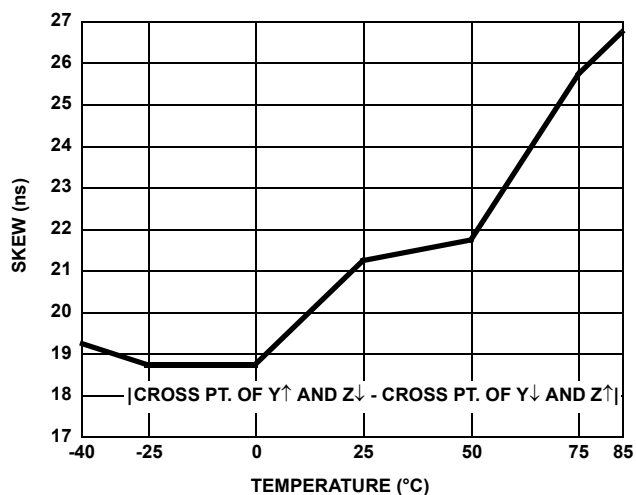


FIGURE 15. DRIVER DIFFERENTIAL SKEW vs TEMPERATURE (ISL83083E, ISL83084E, ISL83085E)

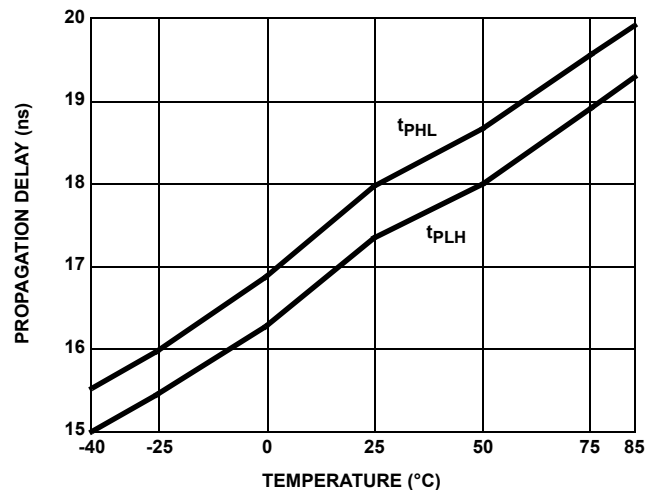
Typical Performance Curves $V_{CC} = 5V$, $T_A = +25^\circ C$; Unless Otherwise Specified (Continued)

FIGURE 16. DRIVER DIFFERENTIAL PROPAGATION DELAY vs TEMPERATURE (ISL83086E, ISL83088E)

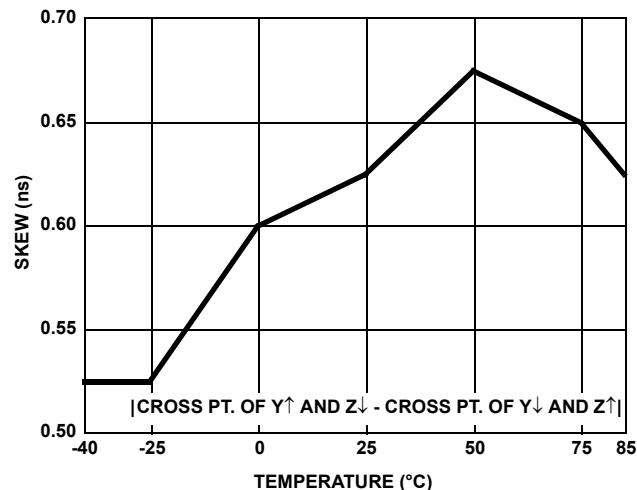


FIGURE 17. DRIVER DIFFERENTIAL SKEW vs TEMPERATURE (ISL83086E, ISL83088E)

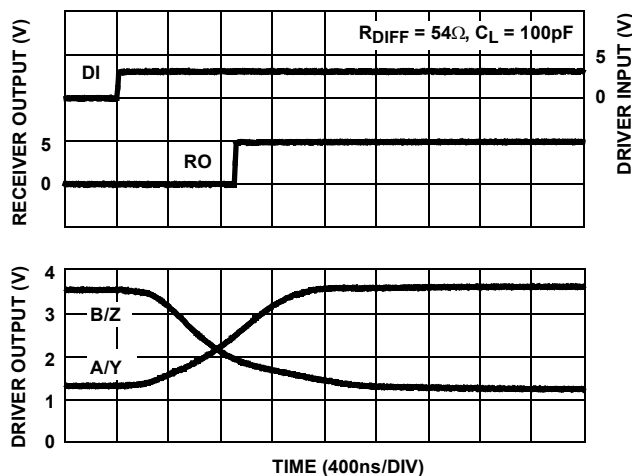


FIGURE 18. DRIVER AND RECEIVER WAVEFORMS, LOW TO HIGH (ISL83080E, ISL83082E)

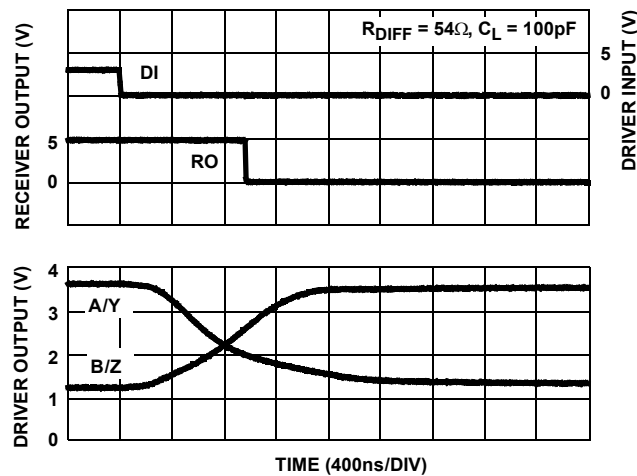


FIGURE 19. DRIVER AND RECEIVER WAVEFORMS, HIGH TO LOW (ISL83080E, ISL83082E)

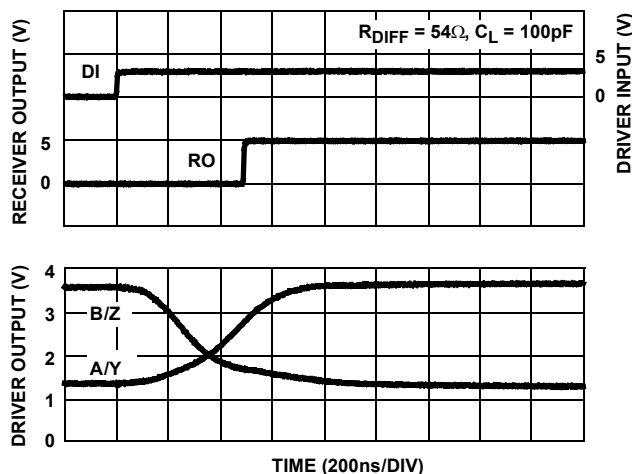


FIGURE 20. DRIVER AND RECEIVER WAVEFORMS, LOW TO HIGH (ISL83083E, ISL83084E, ISL83085E)

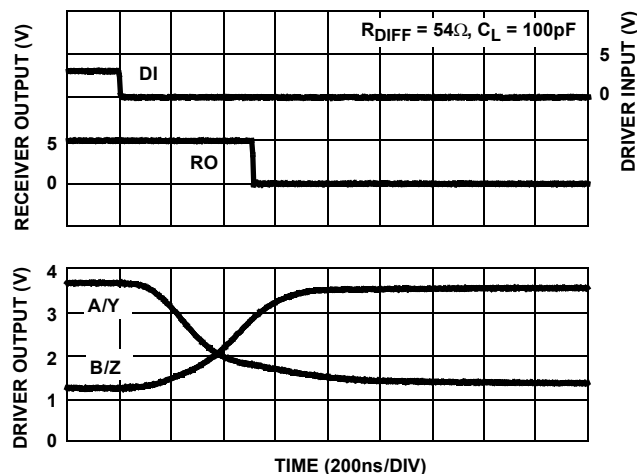


FIGURE 21. DRIVER AND RECEIVER WAVEFORMS, HIGH TO LOW (ISL83083E, ISL83084E, ISL83085E)

Typical Performance Curves $V_{CC} = 5V$, $T_A = +25^\circ C$; Unless Otherwise Specified (Continued)

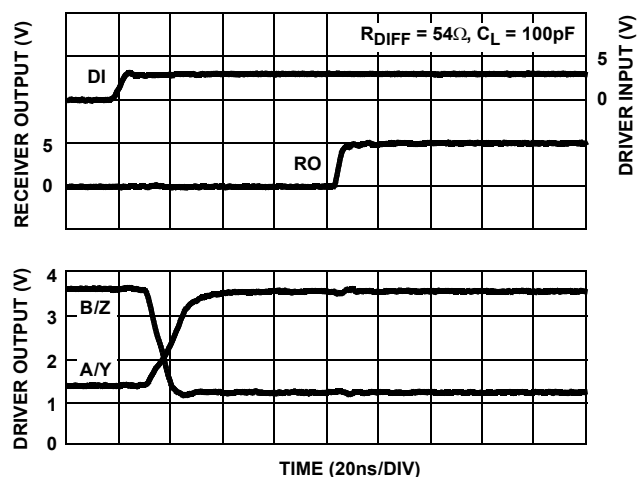


FIGURE 22. DRIVER AND RECEIVER WAVEFORMS, LOW TO HIGH (ISL83086E, ISL83088E)

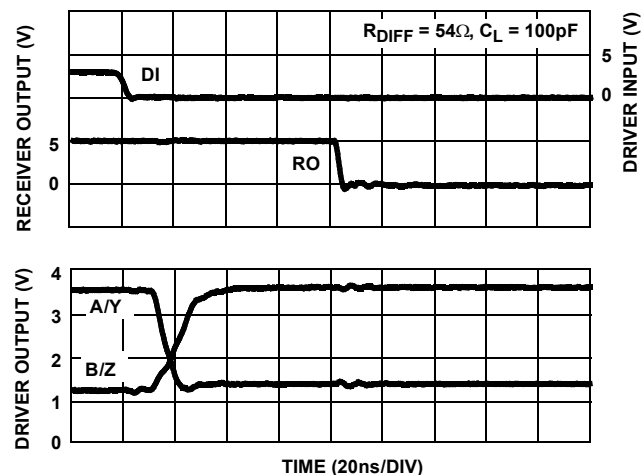


FIGURE 23. DRIVER AND RECEIVER WAVEFORMS, HIGH TO LOW (ISL83086E, ISL83088E)

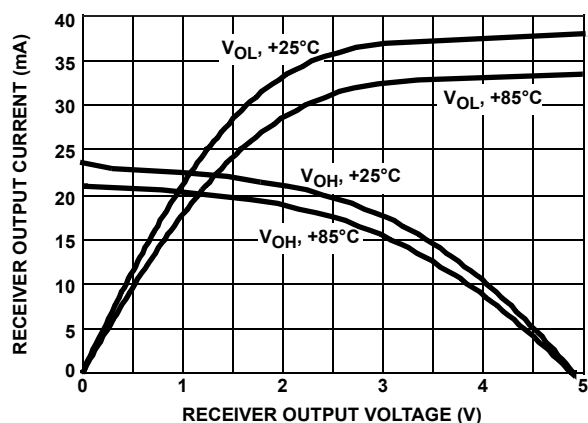


FIGURE 24. RECEIVER OUTPUT CURRENT vs RECEIVER OUTPUT VOLTAGE

Die Characteristics

SUBSTRATE POTENTIAL (POWERED UP):

GND

TRANSISTOR COUNT:

525

PROCESS:

Si Gate BiCMOS

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to the web to make sure that you have the latest revision.

DATE	REVISION	CHANGE
February 15, 2016	FN6085.10	Added Rev History and About Intersil verbiage. Updated "Ordering Information" on page 3. Updated POD M8.118 to current version with following changes: Updated to new Intersil format by adding land pattern and moving dimensions from table onto drawing Corrected lead width dimension in side view 1 from "0.25 - 0.036" to "0.25 - 0.36" Updated POD M10.118 to current version with following change: Updated to new POD template. Added land pattern Updated POD M14.15 to current version with following change: Added land pattern and moved dimensions from table onto drawing. Updated POD M8.15 to current version with following changes: Updated to new POD format by removing table and moving dimensions onto drawing and adding land pattern. Changed in Typical Recommended Land Pattern the following: 2.41(0.095) to 2.20(0.087) 0.76 (0.030) to 0.60(0.023) 0.200 to 5.20(0.205) Changed Note 1 "1982" to "1994"

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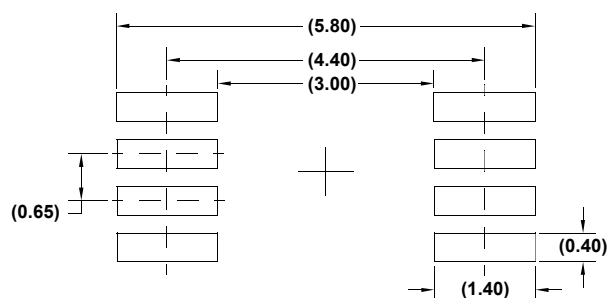
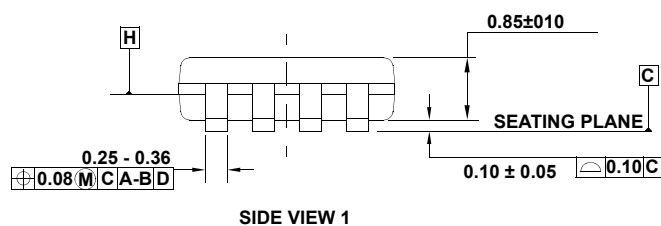
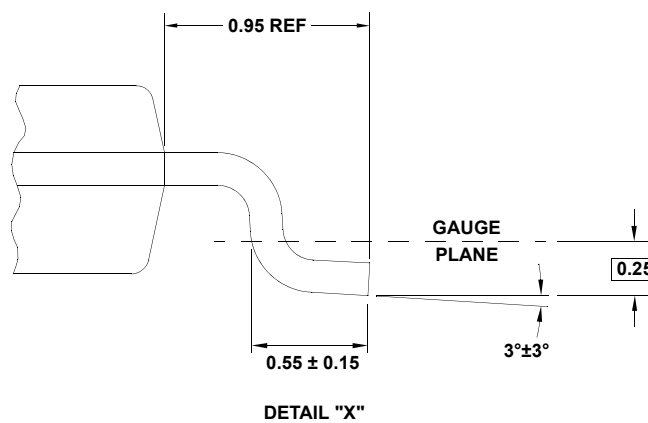
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8 LEAD MINI SMALL OUTLINE PLASTIC PACKAGE

[illegible]

NOTES:

1. Dimensions are in millimeters.
2. Dimensioning and tolerancing conform to JEDEC MO-187-AA and AMSEY14.5m-1994.
3. Plastic or metal protrusions of 0.15mm max per side are not included.
4. Plastic interlead protrusions of 0.15mm max per side are not included.
5.  Dimensions are measured at Datum Plane "H".
6. Dimensions in () are for reference only.

10 LEAD MINI SMALL OUTLINE PLASTIC PACKAGE

[illegible]

1.10 MAX

DETAIL "X"

0.09 - 0.20

SIDE VIEW 2

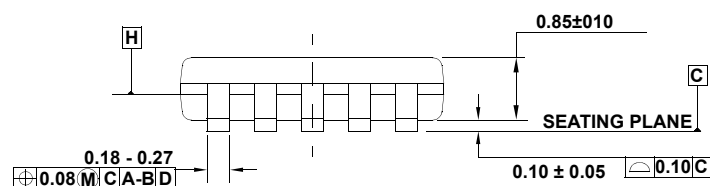
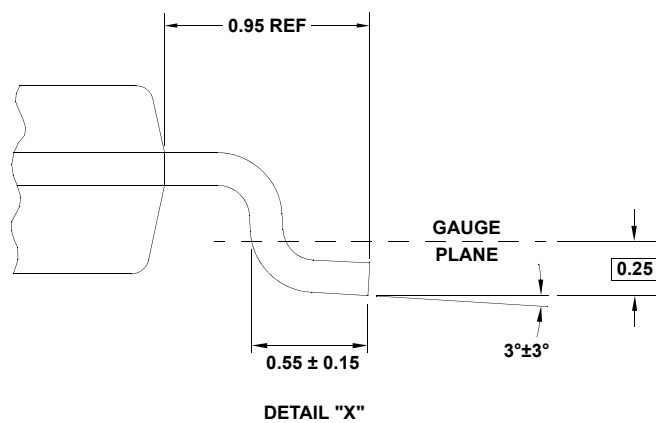
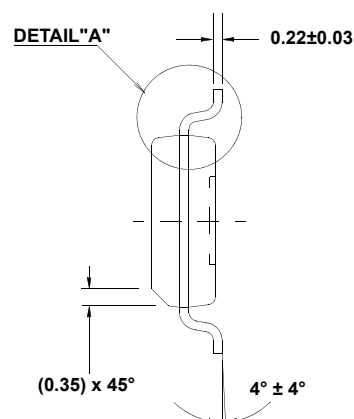


Diagram illustrating a 2D convolution operation. The input is a 5x5 grid (green) with a kernel of size 3x3 (blue) applied to it. The output is a 3x3 grid (red). The diagram shows the spatial dimensions and offsets for the kernel, input, and output. The kernel size is 3.00, the input size is 5.80, and the output size is 4.40. The kernel offset is 1.40, the input offset is 0.50, and the output offset is 0.29.

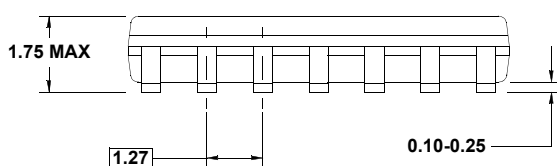
NOTES:

1. Dimensions are in millimeters.
2. Dimensioning and tolerancing conform to JEDEC MO-187-BA and AMSEY14.5m-1994.
3. Plastic or metal protrusions of 0.15mm max per side are not included.
4. Plastic interlead protrusions of 0.15mm max per side are not included.
5.  Dimensions are measured at Datum Plane "H".
6. Dimensions in () are for reference only.

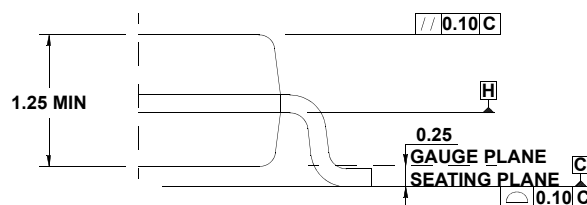
Rev 1, 10/09



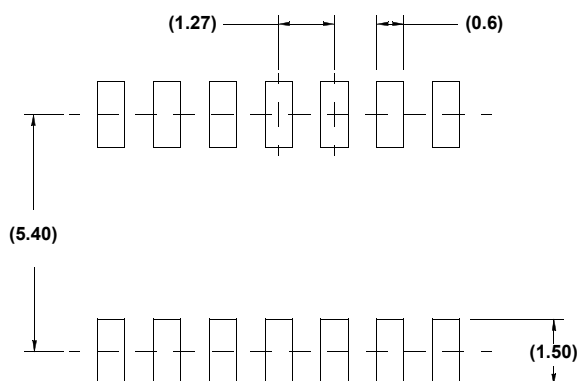
TOP VIEW



SIDE VIEW



DETAIL "A"



TYPICAL RECOMMENDED LAND PATTERN

1. Dimensions are in millimeters.
Dimensions in () for Reference Only.
2. Dimensioning and tolerancing conform to AMSEY14.5m-1994.
3. Datums A and B to be determined at Datum H.
4. Dimension does not include interlead flash or protrusions.
Interlead flash or protrusions shall not exceed 0.25mm per side.
5. The pin #1 identifier may be either a mold or mark feature.
6. Does not include dambar protrusion. Allowable dambar protrusion shall be 0.10mm total in excess of lead width at maximum condition.
7. Reference to JEDEC MS-012-AB.

Rev 4, 1/12



SIDE VIEW "B"



SIDE VIEW "A"



1. Dimensioning and tolerancing per ANSI Y14.5M-1994.
2. Package length does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
3. Package width does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
4. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
5. Terminal numbers are shown for reference only.
6. The lead width as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
7. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.
8. This outline conforms to JEDEC publication MS-012-AA ISSUE C.



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- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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